16 V Rail-to-Rail
Operational Amplifiers

## AD8565/AD8566/AD8567

FEATURES
Single-Supply Operation: 4.5 V to 16 V
Input Capability beyond the Rails
Rail-to-Rail Output Swing
Continuous Output Current: 35 mA
Peak Output Current: 250 mA
Offset Voltage: 10 mV
Slew Rate: $6 \mathrm{~V} / \mu \mathrm{s}$
Unity Gain Stable with Large Capacitive Loads
Supply Current: $700 \mu \mathrm{~A}$ per Amplifier

## APPLICATIONS

LCD Reference Drivers
Portable Electronics
Communications Equipment

## GENERAL DESCRIPTION

The AD8565, AD8566, and AD8567 are low cost, single-supply rail-to-rail input and output operational amplifiers optimized for LCD monitor applications. They are built on an advanced high voltage CBCMOS process. The AD8565 contains a single amplifier, the AD8566 has two amplifiers, and the AD8567 has four amplifiers.

These LCD op amps have high slew rates, 35 mA continuous output drive, 250 mA peak output drive, and high capacitive load drive capability. They have a wide supply range and offset voltages below 10 mV . The AD8565, AD8566, and AD8567 are ideal for LCD grayscale reference buffer and $\mathrm{V}_{\mathrm{COM}}$ applications.
The AD8565, AD8566, and AD8567 are specified over the $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ temperature range. The AD8565 single is available in a 5 -lead SC70 package. The AD8566 dual is available in an 8-lead MSOP package. The AD8567 quad is available in 14-lead TSSOP and 16-lead LFCSP packages.

## PIN CONFIGURATIONS



14-Lead TSSOP (RU Suffix)


16-Lead LFCSP
(CP Suffix)


REV. C

AD8565/AD8566/AD8567-SPECIFICATIONS


| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INPUT CHARACTERISTICS <br> Offset Voltage Offset Voltage Drift Input Bias Current Input Offset Current <br> Input Voltage Range Common-Mode Rejection Ratio <br> Large Signal Voltage Gain <br> Input Impedance Input Capacitance | $\mathrm{V}_{\text {Os }}$ <br> $\Delta \mathrm{V}_{\mathrm{OS}} / \Delta \mathrm{T}$ <br> $\mathrm{I}_{\mathrm{B}}$ <br> $\mathrm{I}_{\text {OS }}$ <br> CMRR <br> AVO <br> $\mathrm{Z}_{\mathrm{IN}}$ <br> $\mathrm{C}_{\mathrm{IN}}$ | $\begin{aligned} & -40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C} \\ & -40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C} \\ & -40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C} \\ & \mathrm{Common}-\mathrm{Mode}^{2} \text { Input } \\ & \mathrm{V}_{\mathrm{CM}}=0 \text { to } \mathrm{V}_{\mathrm{S}}, \\ & -40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C} \\ & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{~V}_{\mathrm{O}}=0.5 \mathrm{~V} \text { to }\left(\mathrm{V}_{\mathrm{S}}-0.5 \mathrm{~V}\right) \end{aligned}$ | $\begin{aligned} & -0.5 \\ & 54 \\ & 3 \end{aligned}$ | $\begin{aligned} & 2 \\ & 5 \end{aligned}$ <br> 80 <br> 1 <br> 95 <br> 10 <br> 400 <br> 1 | $\begin{aligned} & 10 \\ & 600 \\ & 600 \\ & 80 \\ & 130 \\ & \mathrm{~V}_{\mathrm{S}}+0.5 \end{aligned}$ | mV <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> nA <br> nA <br> nA <br> nA <br> V <br> dB <br> $\mathrm{V} / \mathrm{mV}$ <br> $\mathrm{k} \Omega$ <br> pF |
| OUTPUT CHARACTERISTICS <br> Output Voltage High <br> Output Voltage Low <br> Continuous Output Current Peak Output Current | $\begin{aligned} & \mathrm{V}_{\mathrm{OH}} \\ & \\ & \\ & \mathrm{~V}_{\mathrm{OL}} \\ & \\ & \\ & \mathrm{I}_{\mathrm{OUT}} \\ & \mathrm{I}_{\mathrm{PK}} \end{aligned}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{L}}=100 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{S}}=16 \mathrm{~V}, \mathrm{I}_{\mathrm{L}}=5 \mathrm{~mA} \\ & -40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C} \\ & \mathrm{~V}_{\mathrm{S}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{L}}=5 \mathrm{~mA} \\ & -40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C} \\ & \mathrm{I}_{\mathrm{L}}=100 \mu \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{S}}=16 \mathrm{~V}, \mathrm{I}_{\mathrm{L}}=5 \mathrm{~mA} \\ & -40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C} \\ & \mathrm{~V}_{\mathrm{S}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{L}}=5 \mathrm{~mA} \\ & -40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C} \\ & \mathrm{~V}_{\mathrm{S}}=16 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 15.85 \\ & 15.75 \\ & 4.2 \\ & 4.1 \end{aligned}$ | $\mathrm{V}_{\mathrm{S}}-$ 15.95 4.38 5 42 95 35 250 | $\begin{aligned} & 150 \\ & 250 \\ & 300 \\ & 400 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \\ & \mathrm{~V} \\ & \mathrm{~V} \\ & \mathrm{~V} \\ & \mathrm{mV} \\ & \mathrm{mV} \\ & \mathrm{mV} \\ & \mathrm{mV} \\ & \mathrm{mV} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |
| POWER SUPPLY <br> Supply Voltage Power Supply Rejection Ratio Supply Current/Amplifier | $V_{S}$ <br> PSRR $\mathrm{I}_{\mathrm{SY}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=4 \mathrm{~V} \text { to } 17 \mathrm{~V}, \\ & -40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C} \\ & \mathrm{~V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{S}} / 2, \text { No Load } \\ & -40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & 4.5 \\ & 70 \end{aligned}$ | $\begin{aligned} & 90 \\ & 700 \end{aligned}$ | 16 $850$ <br> 1 | V <br> dB <br> $\mu \mathrm{A}$ <br> mA |
| DYNAMIC PERFORMANCE <br> Slew Rate Gain Bandwidth Product Phase Margin Channel Separation | $\begin{aligned} & \text { SR } \\ & \text { GBP } \\ & \text { Øо } \end{aligned}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=200 \mathrm{pF} \\ & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=10 \mathrm{pF} \\ & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=10 \mathrm{pF} \end{aligned}$ | 4 | $\begin{aligned} & 6 \\ & 5 \\ & 65 \\ & 75 \end{aligned}$ |  | V/us <br> MHz <br> Degrees <br> dB |
| NOISE PERFORMANCE <br> Voltage Noise Density Current Noise Density | $\begin{aligned} & \mathrm{e}_{\mathrm{n}} \\ & \mathrm{e}_{\mathrm{n}} \\ & \mathrm{i}_{\mathrm{n}} \end{aligned}$ | $\begin{aligned} & \mathrm{f}=1 \mathrm{kHz} \\ & \mathrm{f}=10 \mathrm{kHz} \\ & \mathrm{f}=10 \mathrm{kHz} \end{aligned}$ |  | $\begin{aligned} & 26 \\ & 25 \\ & 0.8 \end{aligned}$ |  | $\begin{aligned} & \mathrm{nV} / \sqrt{\mathrm{Hz}} \\ & \mathrm{nV} / \sqrt{\mathrm{Hz}} \\ & \mathrm{pA} / \sqrt{\mathrm{Hz}} \end{aligned}$ |

[^0]
## ABSOLUTE MAXIMUM RATINGS*

| Supply Voltage (V) | V |
| :---: | :---: |
| Input Voltage | -0.5 V to $\mathrm{V}_{\mathrm{S}}+0.5 \mathrm{~V}$ |
| Differential Input Voltage |  |
| Storage Temperature Range | C to $+150^{\circ} \mathrm{C}$ |
| Operating Temperature Range | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Junction Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
|  | $300^{\circ} \mathrm{C}$ |

*Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

| Package Type | $\boldsymbol{\theta}_{\mathbf{J A}}{ }^{\mathbf{1}}$ | $\boldsymbol{\theta}_{\mathbf{J C}}$ | Unit |
| :--- | :--- | :--- | :--- |
| 5-Lead SC70 (KS) | 376 | 126 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| 8-Lead MSOP (RM) | 210 | 45 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| 14-Lead TSSOP (RU) | 180 | 35 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| 16-Lead LFCSP (CP) | $38^{2}$ | $30^{2}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## NOTES

${ }^{1} \theta_{\mathrm{JA}}$ is specified for worst-case conditions, i.e., $\theta_{\mathrm{JA}}$ is specified for a device soldered onto a circuit board for surface-mount packages.
${ }^{2} \mathrm{DAP}$ is soldered down to PCB.

ORDERING GUIDE

| Model | Temperature <br> Range | Package Description | Package <br> Option | Branding |
| :--- | :--- | :--- | :--- | :--- |
| AD8565AKS-R2 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 5-Lead Thin Shrink Small Outline Transistor Package | KS-5 | ASA |
| AD8565AKS-REEL7 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 5-Lead Thin Shrink Small Outline Transistor Package | KS-5 | ASA |
| AD8565AKSZ-REEL7* | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 5-Lead Thin Shrink Small Outline Transistor Package | KS-5 | ASA |
| AD8566ARM-R2 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 8-Lead Micro Small Outline Package | RM-8 | ATA |
| AD8566ARM-REEL | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 8-Lead Micro Small Outline Package | RM-8 | ATA |
| AD8566ARMZ-REEL* | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 8-Lead Micro Small Outline Package | RM-8 | ATA |
| AD8567ARU | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 14-Lead Thin Shrink Small Outline Package | RU-14 |  |
| AD8567ARU-REEL | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 14-Lead Thin Shrink Small Outline Package | RU-14 |  |
| AD8567ARUZ* | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 14-Lead Thin Shrink Small Outline Package | RU-14 |  |
| AD8567ARUZ-REEL* | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 14-Lead Thin Shrink Small Outline Package | RU-14 |  |
| AD8567ACP-R2 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 16-Lead Lead Frame Chip Scale Package | CP-16 |  |
| AD8567ACP-REEL | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 16-Lead Lead Frame Chip Scale Package | CP-16 |  |
| AD8567ACP-REEL7 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 16-Lead Lead Frame Chip Scale Package | CP-16 |  |
| AD8567ACPZ-REEL* | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 16-Lead Lead Frame Chip Scale Package | $\mathrm{CP}-16$ |  |
| AD8567ACPZ-REEL7* | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 16-Lead Lead Frame Chip Scale Package | $\mathrm{CP}-16$ |  |

${ }^{*} \mathrm{Z}=\mathrm{Pb}$-free part.

## CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD8565/AD8566/AD8567 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

## AD8565/AD8566/AD8567-Typical Performance Characteristics



TPC 1. Input Offset Voltage vs. Temperature


TPC 2. Current Noise Density vs. Frequency


TPC 3. Small Signal Transient Response


TPC 4. Voltage Noise Density vs. Frequency


TPC 5. Supply Current/Amplifier vs. Supply Voltage


TPC 6. Supply Current/Amplifier vs. Temperature


TPC 7. Small Signal Overshoot vs. Load Capacitance


TPC 8. Closed-Loop Output Swing vs. Frequency


TPC 9. Closed-Loop Gain vs. Frequency


TPC 10. Open-Loop Gain and Phase Shift vs. Frequency


TPC 11. Output Voltage to Supply Rail vs. Load Current


TPC 12. Output Voltage Swing to Rail vs. Temperature

## AD8565/AD8566/AD8567



TPC 13. Output Voltage Swing to Rail vs. Temperature


TPC 14. Closed-Loop Output Impedance vs. Frequency


TPC 15. Common-Mode Rejection Ratio vs. Frequency


TPC 16. Power Supply Rejection Ratio vs. Frequency


TPC 17. No Phase Reversal


TPC 18. Input Offset Voltage Distribution


TPC 19. Input Offset Current vs. Temperature


TPC 20. Input Bias Current vs. Temperature


TPC 21. Channel A vs. Channel B Crosstalk


TPC 22. Frequency vs. Common-Mode Voltage ( $V_{S}=16$ V)


TPC 23. Frequency vs. Common-Mode Voltage $\left(V_{S}=5.0 \mathrm{~V}\right)$

## AD8565/AD8566/AD8567

## APPLICATIONS

## Theory of Operation

The AD856x family is designed to drive large capacitive loads in LCD applications. It has high output current drive, rail-to-rail input/output operation, and is powered from a single 16 V supply. It is also intended for other applications where low distortion and high output current drive are needed.
Figure 1 illustrates a simplified equivalent circuit for the AD 856 x . The rail-to-rail bipolar input stage is composed of two PNP differential pairs, Q4 to Q5 and Q10 to Q11, operating in series with diode protection networks, D1 to D2. Diode network D 1 to D 2 serves as protection against large transients for Q4 to Q5 to accommodate rail-to-rail input swing. D5 to D6 protect Q10 to Q11 against Zenering. In normal operation, Q10 to Q11 are off and their input stage is buffered from the operational amplifier inputs by Q6 to D3 and Q8 to D4. Operation of the input stage is best understood as a function of applied common-mode voltage: when the inputs of the AD856x are biased midway between the supplies, the differential signal path gain is controlled by resistive loads (via R9, R10) Q4 to Q5. As the input common-mode level is reduced toward the negative supply ( $\mathrm{V}_{\mathrm{NEG}}$ or GND), the input transistor current sources, I1 and I2, are forced into saturation, thereby forcing the Q6 to D3 and Q8 to D4 networks into cutoff. However, Q4 to Q5 remain active, providing input stage gain. Inversely, when common-mode input voltage is increased toward the positive supply, Q 4 to Q 5 are driven into cutoff, Q3 is driven into saturation, and Q4 becomes active, providing bias to the Q10 to Q11 differential pair. The point at which Q10 to Q11 differential pair becomes active is approximately equal to $\left(\mathrm{V}_{\mathrm{POS}}-1 \mathrm{~V}\right)$.


Figure 1. AD856x Equivalent Input Circuit

The benefit of this type of input stage is low bias current. The input bias current is the sum of base currents of Q4 to Q5 and Q6 to Q8 over the range from $\left(\mathrm{V}_{\mathrm{NEG}}+1 \mathrm{~V}\right)$ to $\left(\mathrm{V}_{\mathrm{POS}}-1 \mathrm{~V}\right)$. Outside of this range, input bias current is dominated by the sum of base currents of Q10 to Q11 for input signals close to $\mathrm{V}_{\mathrm{NEG}}$ and of Q6 to Q8 (Q10 to Q11) for signals close to $\mathrm{V}_{\mathrm{Pos}}$. From this type of design, the input bias current of AD856x not only exhibits different amplitude but also exhibits different polarities. Figure 2 provides the characteristics of the input bias current versus the common-mode voltage. It is important to keep in mind that the source impedances driving the AD856x inputs are balanced for optimum dc and ac performance.


Figure 2. AD856x Input Bias Current vs. Common-Mode Voltage
In order to achieve rail-to-rail output performance, the AD856x design uses a complementary common-source (or gmRL) output. This configuration allows output voltages to approach the power supply rails, particularly if the output transistors are allowed to enter the triode region on extremes of signal swing, which are limited by $\mathrm{V}_{\mathrm{GS}}$, the transistor sizes, and output load current. Also, this type of output stage exhibits voltage gain in an open-loop gain configuration. The amount of gain depends on the total load resistance at the output of the AD856x.

## Input Overvoltage Protection

As with any semiconductor device, whenever the input exceeds either supply voltages, attention needs to be paid to the input overvoltage characteristics. As an overvoltage occurs, the amplifier could be damaged, depending on the voltage level and the magnitude of the fault current. When the input voltage exceeds either supply by more than 0.6 V , internal pn junctions allow current to flow from the input to the supplies.
This input current is not inherently damaging to the device as long as it is limited to 5 mA or less. If a condition exists using the AD 856 x where the input exceeds the supply more than 0.6 V , an external series resistor should be added. The size of the resistor can be calculated by using the maximum overvoltage divided by 5 mA . This resistance should be placed in series with either input exposed to an overvoltage.

## Output Phase Reversal

The AD856x family is immune to phase reversal. Although the device's output will not change phase, large currents due to input overvoltage could damage the device. In applications where the possibility of an input voltage exceeding the supply voltage exists, overvoltage protection should be used as described in the previous section.

## Power Dissipation

The maximum allowable internal junction temperature of $150^{\circ} \mathrm{C}$ limits the AD856x family's maximum power dissipation of AD856x devices. As the ambient temperature increases, the maximum power dissipated by AD856x devices must decrease linearly to maintain the maximum junction temperature. If this maximum junction temperature is exceeded momentarily, the device will still operate properly once the junction temperature is reduced below $150^{\circ} \mathrm{C}$. If the maximum junction temperature is exceeded for an extended period of time, overheating could lead to permanent damage of the device.
The maximum safe junction temperature, $T_{J M A X}$, is $150^{\circ} \mathrm{C}$. Using the following formula, we can obtain the maximum power that an AD 856 x device can safely dissipate as a function of temperature:

$$
P_{D I S S}=T_{J M A X}-T_{A} / \theta_{J A}
$$

where:
$P_{\text {DISS }}=$ the AD 856 x power dissipation.
$T_{J M A X}=$ the AD 856 x maximum allowable junction temperature $\left(150^{\circ} \mathrm{C}\right)$.
$T_{A}=$ the ambient temperature of the circuit.
$\theta_{J A}=$ the AD856x package thermal resistance, junction-to-ambient.
The power dissipated by the device can be calculated as

$$
P_{D I S S}=\left(V_{S}-V_{O U T}\right) \times I_{L O A D}
$$

where:
$V_{S}=$ the supply voltage.
$V_{\text {OUT }}=$ the output voltage.
$I_{L O A D}=$ the output load current.
Figure 3 shows the maximum power dissipation versus temperature. To achieve proper operation, use the previous equation to calculate $P_{\text {DISS }}$ for a specific package at any given temperature or use the figure below.


Figure 3. Maximum Power Dissipation vs. Temperature for 5-, 8-, and 14-Lead Packages

## Total Harmonic Distortion + Noise (THD+N)

The AD856x family features low total harmonic distortion. Figure 4 shows a graph of THD +N versus frequency. The THD +N for the AD856x over the entire supply range is below $0.008 \%$. When the device is powered from a 16 V supply, the THD+N stays below $0.003 \%$. Figure 4 shows the AD8566 in a unity noninverting configuration.


Figure 4. THD $+N$ vs. Frequency Graph

## Short-Circuit Output Conditions

The AD856x family does not have internal short-circuit protection circuitry. As a precautionary measure, it is recommended not to short the output directly to the positive power supply or to ground.
It is not recommended to operate the AD856x with more than 35 mA of continuous output current. The output current can be limited by placing a series resistor at the output of the amplifier whose value can be derived using the following equation:

$$
R_{X} \geq \frac{V_{S}}{35 \mathrm{~mA}}
$$

For a 5 V single-supply operation, $R_{X}$ should have a minimum value of $143 \Omega$.

## LCD Panel Applications

The AD856x amplifier is designed for LCD panel applications or applications where large capacitive load drive is required. It can instantaneously source/sink greater than 250 mA of current. At unity gain, it can drive $1 \mu \mathrm{~F}$ without compensation. This makes the AD856x ideal for LCD $\mathrm{V}_{\mathrm{COM}}$ driver applications.
To evaluate the performance of the AD856x family, a test circuit was developed to simulate the $\mathrm{V}_{\mathrm{COM}}$ driver application for an LCD panel.

## AD8565/AD8566/AD8567

Figure 5 shows the test circuit. Series capacitors and resistors connected to the output of the op amp represent the load of the LCD panel. The $300 \Omega$ and $3 \mathrm{k} \Omega$ feedback resistors are used to improve settling time. This test circuit simulates the worst-case scenario for a $\mathrm{V}_{\text {СОм }}$. It drives a represented load that is connected to a signal switched symmetrically around $\mathrm{V}_{\mathrm{COM}}$. Figure 6 displays a scope photo of the instantaneous output peak current capability of the AD856x family.


Figure 5. $V_{\text {сом }}$ Test Circuit with Supply Voltage at 16 V


Figure 6. Scope Photo of the $V_{\text {Сом }}$ Instantaneous Peak Current

## OUTLINE DIMENSIONS

5-Lead Thin Shrink Small Outline Transistor Package [SC70]
(KS-5)
Dimensions shown in millimeters


8-Lead Micro Small Outline Package [MSOP]
(RM-8)
Dimensions shown in millimeters


COMPLIANT TO JEDEC STANDARDS MO-187AA

14-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-14)
Dimensions shown in millimeters


## OUTLINE DIMENSIONS

## 16-Lead Lead Frame Chip Scale Package [LFCSP] $4 \mathrm{~mm} \times 4 \mathrm{~mm}$ Body <br> (CP-16) <br> Dimensions shown in millimeters



## Revision History

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## X-ON Electronics

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9316401MXA 5962-9452101M2A EV1HMC1160LP5 EV1HMC305SLP4 EV1HMC306AMS10 EV1HMC557ALC4 EV1HMC6146BLC5A
EV1HMC6832ALP5L EV1HMC7912LP5 EV1HMC7992LP3D EV1HMC951BLP4 EV-AD5443/46/53SDZ EV-ADF70301-433AZ EV-
ADF70301-868BZ EV-ADUCM322IQSPZ EV-ADUCM322QSPZ EVAL01-HMC1048LC3B EVAL01-HMC1055LP2C EVAL01-
HMC1063LP3 EVAL01-HMC197B EVAL01-HMC760LC4B EVAL01-HMC829LP6GE EVAL01-HMC833LP6GE EVAL01-
HMC835LP6G EVAL01-HMC985LP4KE EVAL01-HMC987LP5E EVAL01-HMC988LP3E EVAL01-HMC995LP5GE EVAL02-
HMC1034LP6G EVAL-3CH4CHSOICEBZ EVAL-AD1871EBZ EVAL-AD5063EBZ EVAL-AD5064EBZ EVAL-AD5171DBZ


[^0]:    Specifications subject to change without notice.

